NPN Epitaxial Planar Silicon Transistor



2SD1685

20V/5A Switching Applications

Applications

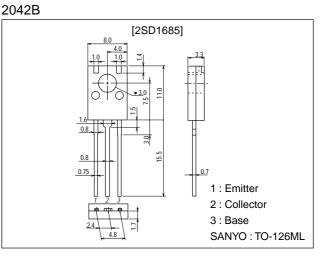
· Strobe, voltage regulators, relay drivers, lamp drivers.

Features

- \cdot Low saturation voltage.
- · Large current capacity.
- · Fast switching time.
- No insulator required when mounting because the leadframe of the chip is covered with plastic.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

-				
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		60	V
Collector-to-Emitter Voltage	VCEO		20	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		5	A
Collector Current (Pulse)	I _{CP}		8	A
Collector Dissipation	PC		1.5	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =50V, I _E =0			100	nA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			100	nA
DC Current Gain	h _{FE} 1	V _{CE} =2V, I _C =500mA	120*		560*	
	h _{FE} 2	V _{CE} =2V, I _C =3A	95			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =50mA		120		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		45		pF
* The 2SD1685 is classified by 500mA here as follows :				Continued on next pag		

* The 2SD1685 is classified by 500mA h_{FE} as follows :

120 E 200 160 F 320 280 G 560

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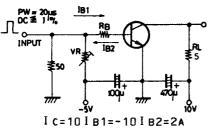
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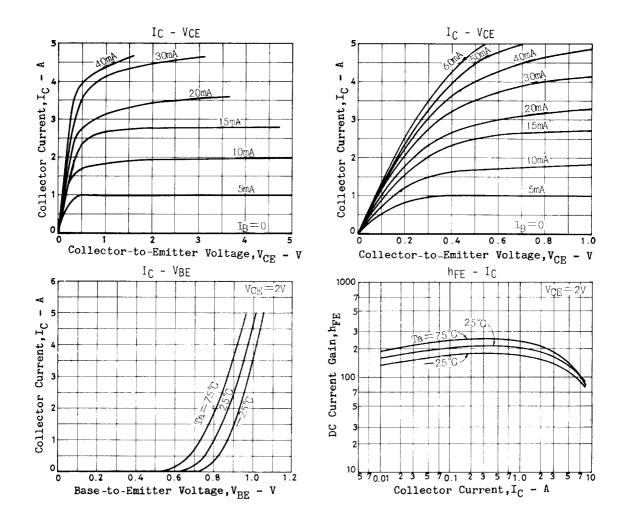
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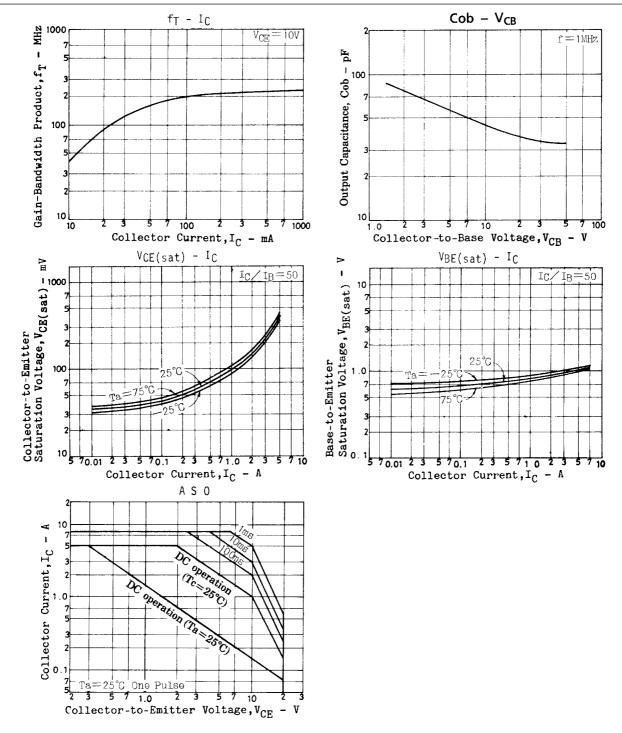
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =3A, I _B =60mA		220	500	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =3A, I _B =60mA			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	20			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	6			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	^t stg	See specified Test Circuit.		300		ns
Fall Time	t _f	See specified Test Circuit.		40		ns

Switching Time Test Circuit



Unit (resistance : Ω , capacitance : F)





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